



60V N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

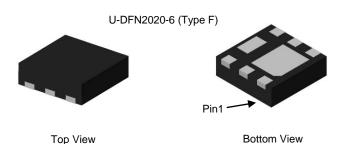
BV _{DSS}	R _{DS(ON)} Max	$I_{D \text{ Max}}$ $T_{A} = +25^{\circ}\text{C}$		
60V	16mΩ @ V _{GS} = 10V	8.9A		
	$27m\Omega @ V_{GS} = 4.5V$	6.8A		

Description

This new generation MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) and yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

Applications

- Load Switch
- Adaptor Switch
- Notebook PC

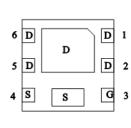


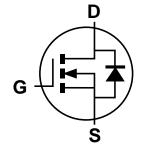
Features and Benefits

- 100% Unclamped Inductive Switch (UIS) Test in Production
- 0.6mm Profile Ideal for Low Profile Applications
- PCB Footprint of 4mm²
- Low On-Resistance
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: U-DFN2020-6 (Type F)
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 @4
- Weight: 0.007 grams (Approximate)





Pin Out Bottom View

Equivalent Circuit

Ordering Information (Note 4)

Part Number	Marking	Reel Size (inches)	Quantity per Reel
DMT6016LFDF-7	T6	7	3,000
DMT6016LFDF-13	T6	13	10,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



T6 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: D = 2016) M = Month (ex: 9 = September)

Date Code Key

Year	2014	20	015	2016	2017	20	018	2019	2020	2	021	2022
Code	В	(С	D	Е		F	G	Н		I	J
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	1	5	6	7	8	a	0	N	ח



Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V_{DSS}	60	V		
Gate-Source Voltage			V_{GSS}	±20	V
Continuous Dusin Courset (Nata CVV 40V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	l _D	8.9 7.1	А
Continuous Drain Current (Note 6) V _{GS} = 10V	t<10s	$T_A = +25$ °C $T_A = +70$ °C	I _D	11.1 8.9	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	60	Α		
Maximum Body Diode Continuous Current	Is	2.2	Α		
Avalanche Current (Note 7) L = 0.1mH	I _{AS}	15.3	Α		
Avalanche Energy (Note 7) L = 0.1mH	E _{AS}	11.7	mJ		

Thermal Characteristics

Characteristic	Symbol	Value	Unit	
Total Dower Dissipation (Note 5)	$T_A = +25$ °C	D	0.82	W
Total Power Dissipation (Note 5)	$T_A = +70^{\circ}C$	P_{D}	0.52	
Thormal Booistones, Junction to Ambient (Note 5)	Steady State	D	153	°C/W
Thermal Resistance, Junction to Ambient (Note 5)	t<10s	$R_{\theta JA}$	97	
Total Dower Dissipation (Note 6)	$T_A = +25$ °C	D	1.9	W
Total Power Dissipation (Note 6)	$T_A = +70^{\circ}C$	P_{D}	1.2	
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	D	66	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	t<10s	$R_{\theta JA}$	42	
Thermal Resistance, Junction to Case (Note 6)	$R_{ heta JC}$	14.7		
Operating and Storage Temperature Range		$T_{J_i} T_{STG}$	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV _{DSS}	60	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	1	μA	$V_{DS} = 48V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V _{GS(TH)}	1.0	_	3.0	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
Static Drain-Source On-Resistance			12.2	16	mΩ	$V_{GS} = 10V, I_D = 10A$	
Static Dialii-Source On-Resistance	R _{DS(ON)}	_	17.2	27	11122	$V_{GS} = 4.5V, I_D = 6A$	
Diode Forward Voltage	V _{SD}	_	0.7	1.2	V	$V_{GS} = 0V$, $I_S = 1A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	C _{iss}	1	864			$V_{DS} = 30V, V_{GS} = 0V$ f = 1.0MHz	
Output Capacitance	Coss	1	282		pF		
Reverse Transfer Capacitance	C _{rss}		27.1				
Gate Resistance	Rg		1.35	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge (V _{GS} = 10V)	Q_g		17	_			
Total Gate Charge (V _{GS} = 4.5V)	Q_{g}	_	8.4	_	nC	V 20V L 40A	
Gate-Source Charge	Q_gs		3.1	_	110	$V_{DS} = 30V, I_{D} = 10A$	
Gate-Drain Charge	Q_{gd}	_	4.3	_			
Turn-On Delay Time	t _{D(ON)}	_	3.4	_			
Turn-On Rise Time	t _R	_	5.2	_	nS	$V_{GS} = 10V, V_{DD} = 30V, R_{q} = 6\Omega,$	
Turn-Off Delay Time	t _{D(OFF)}	_	12.9	_	113	I _D = 10A	
Turn-Off Fall Time	t _F		6.8	_			
Body Diode Reverse Recovery Time	t _{RR}		22	_	nS	$I_S = 10A$, $dI/dt = 100A/\mu s$	
Body Diode Reverse Recovery Charge	Q_{RR}		11.1	_	nC	$I_S = 10A$, $dI/dt = 100A/\mu s$	

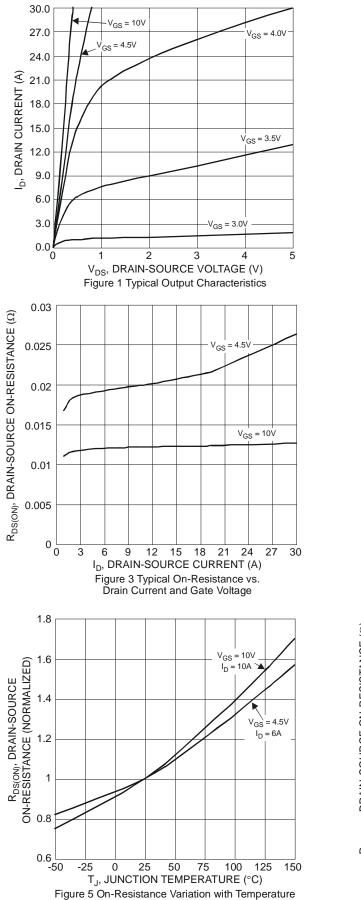
Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

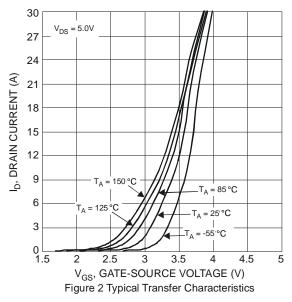
7. I_{AS} and E_{AS} rating are based on low frequency and duty cycles to keep $T_J = +25$ °C.

8. Short duration pulse test used to minimize self-heating effect.

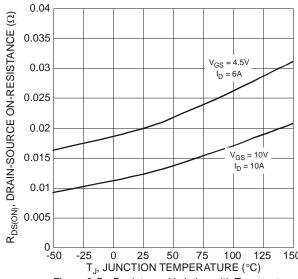
9. Guaranteed by design. Not subject to product testing.







0.025 $R_{DS(ON)}$, DRAIN-SOURCE ON-RESISTANCE (Ω) $V_{GS} = 10V$ T_A = 150 °C T_A = 125 °C 0.02 T_A = 85 °C 0.015 $T_A = 25$ °C 0.01 $\dot{\Gamma}_A = -55^{\circ}C$ 0.005 2 8 10 12 14 I_D, DRAIN CURRENT (A) Figure 4 Typical On-Resistance vs. Drain Current and Temperature





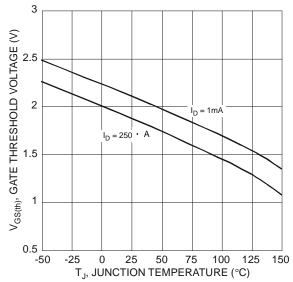


Figure 7 Gate Threshold Variation vs. Ambient Temperature

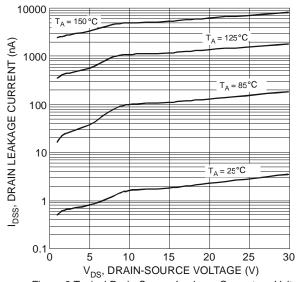
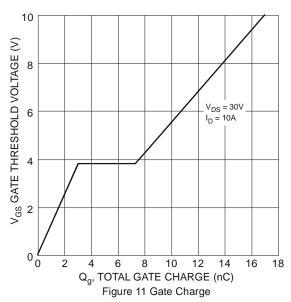
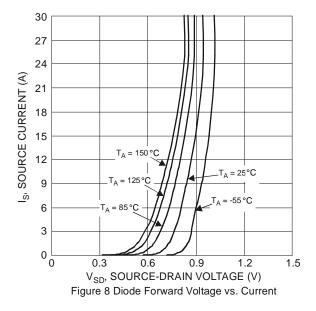
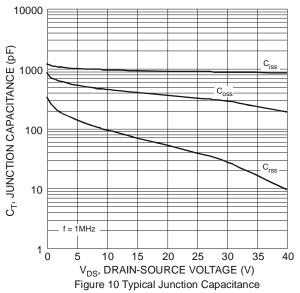
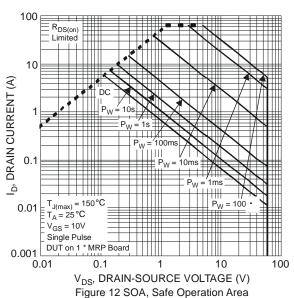


Figure 9 Typical Drain-Source Leakage Current vs. Voltage

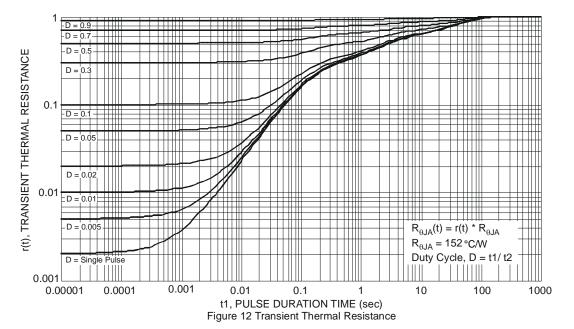










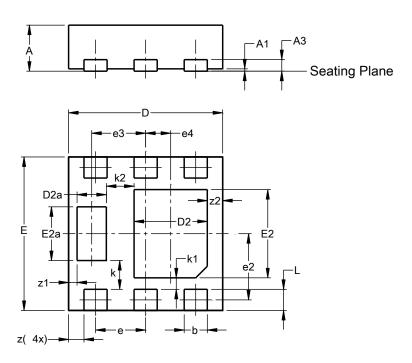




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN2020-6 (Type F)

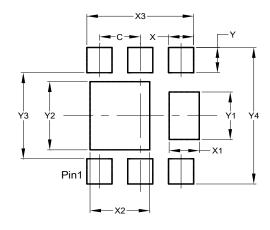


U-DFN2020-6								
(Type F)								
Dim	Min	Max	Тур					
Α	0.57	0.63	0.60					
A1	0.00	0.05	0.03					
А3	1	-	0.15					
b	0.25	0.35	0.30					
D	1.95	2.05	2.00					
D2	0.85	1.05	0.95					
D2a	0.33	0.43	0.38					
Е	1.95	2.05	2.00					
E2	1.05	1.25	1.15					
E2a	0.65	0.75	0.70					
е		0.65 BS	С					
e2).863 BS						
е3		0.70 BS						
e4).325 BS	SC					
k		0.37 BS	С					
k1	0.15 BSC							
k2	0.36 BSC							
L	0.225 0.325 0.275							
Z		0.20 BS	С					
z 1	0.110 BSC							
z2		0.20 BS	С					
All C	imens	ions in	mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN2020-6 (Type F)



Dimensions	Value (in mm)
С	0.650
X	0.400
X1	0.480
X2	0.950
Х3	1.700
Y	0.425
Y1	0.800
Y2	1.150
Y3	1.450
Y4	2.300



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